TOSHIBA Intelligent Power Module Silicon N Channel IGBT

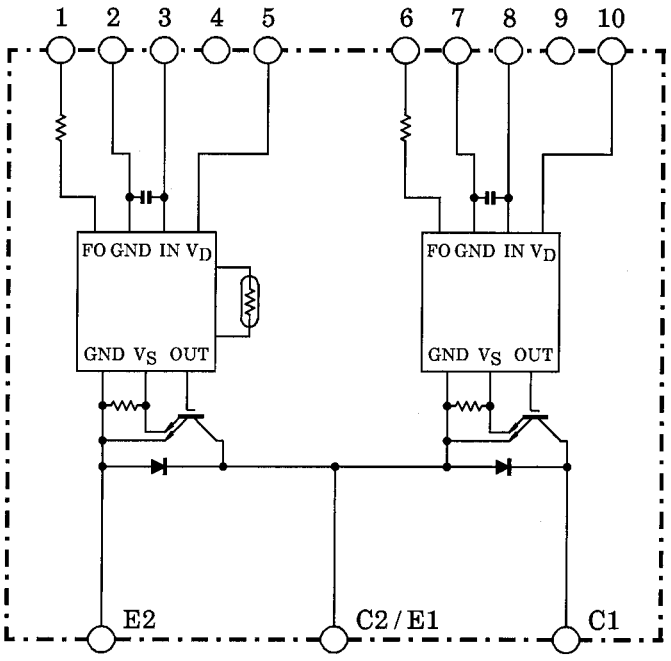
MIG400J101H

High Power Switching Applications

Motor Control Applications

- Integrates inverter power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over temperature) in one package.
- The electrodes are isolated from case.
- High speed type IGBT : $V_{CE\ (sat)}$ = 2.5V (max)
  t_{off} = 2.0μs (max)
  t_{rr} = 0.15μs (max)
- Package dimensions : TOSHIBA 2-121A1A
- Weight : 510g

Equivalent Circuit



1. FO (L) 2. GND (L) 3. IN (L) 4. Open 5. V_D (L)
6. FO (H) 7. GND (H) 8. IN (H) 9. Open 10. V_D (H)

Maximum Ratings (T_j = 25°C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V_{CC}	450	V
	Collector-emitter voltage	—	V_{CES}	600	V
	Collector current	Tc = 25°C, DC	I_C	400	A
	Forward current	Tc = 25°C, DC	I_F	400	A
	Collector power dissipation	Tc = 25°C	P_C	1600	W
	Junction temperature	—	T_j	150	°C
Control	Control supply voltage	V_D-GND terminal	V_D	20	V
	Input voltage	IN-GND terminal	V_{IN}	20	V
	Fault output voltage	FO-GND (L) terminal	V_{FO}	20	V
	Fault output current	FO sink current	I_{FO}	14	mA
Module	Operating temperature	—	T_C	−20 ~ +100	°C
	Storage temperature range	—	T_{stg}	−40 ~ +125	°C
	Isolation voltage	AC 1 minute,	V_{ISO}	2500	V
	Screw torque	M6	—	3	Nm

Electrical Characteristics (T_j = 25°C)

a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Typ.	Max	Unit
Collector cut-off current	I_{CEX}	V_{CE} = 600V	T_j = 25°C	—	—	2	mA
			T_j = 125°C	—	—	40	
Collector-emitter saturation voltage	$V_{CE\ (sat)}$	V_D = 15V, I_C = 400A V_{IN} = 3V → 0V	T_j = 25°C	—	2.0	2.5	V
			T_j = 125°C	—	2.0	—	
Forward voltage	V_F	I_F = 400A		—	2.1	2.7	V
Switching time	t_{on}	V_{CC} = 300V, I_C = 400A V_D = 15V, V_{IN} = 3V ↔ 0V Inductive load (Note 1)		1.4	2.1	2.8	μs
	$t_{c\ (on)}$			—	1.2	1.8	
	t_{rr}			—	0.08	0.15	
	t_{off}			—	1.2	2.0	
	$t_{c\ (off)}$			—	0.3	0.6	

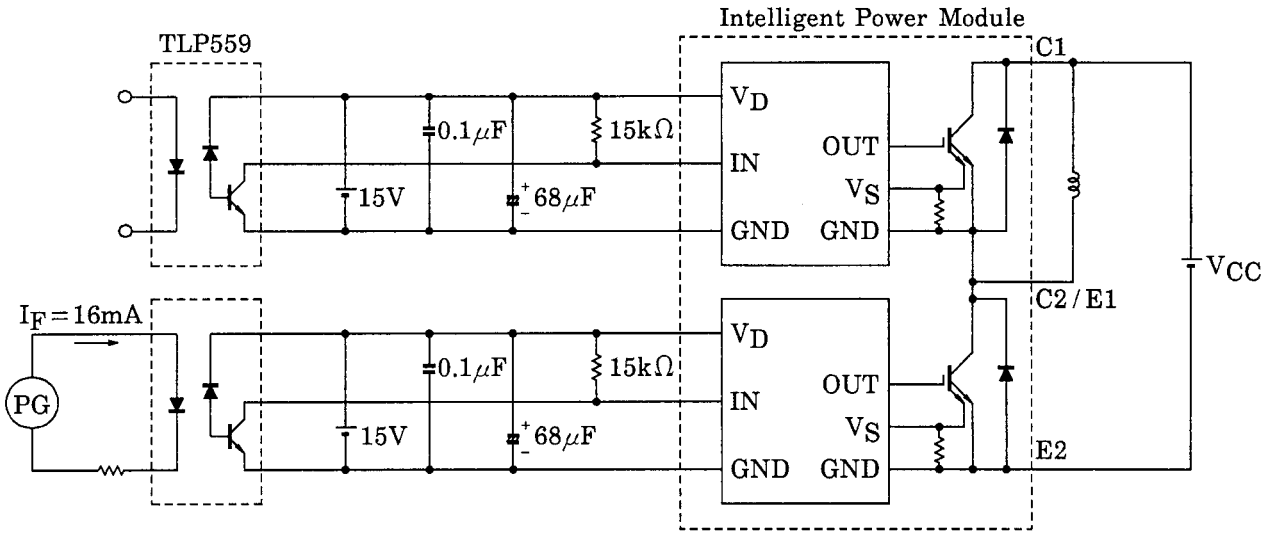
b. Control Stage (T_j = 25°C)

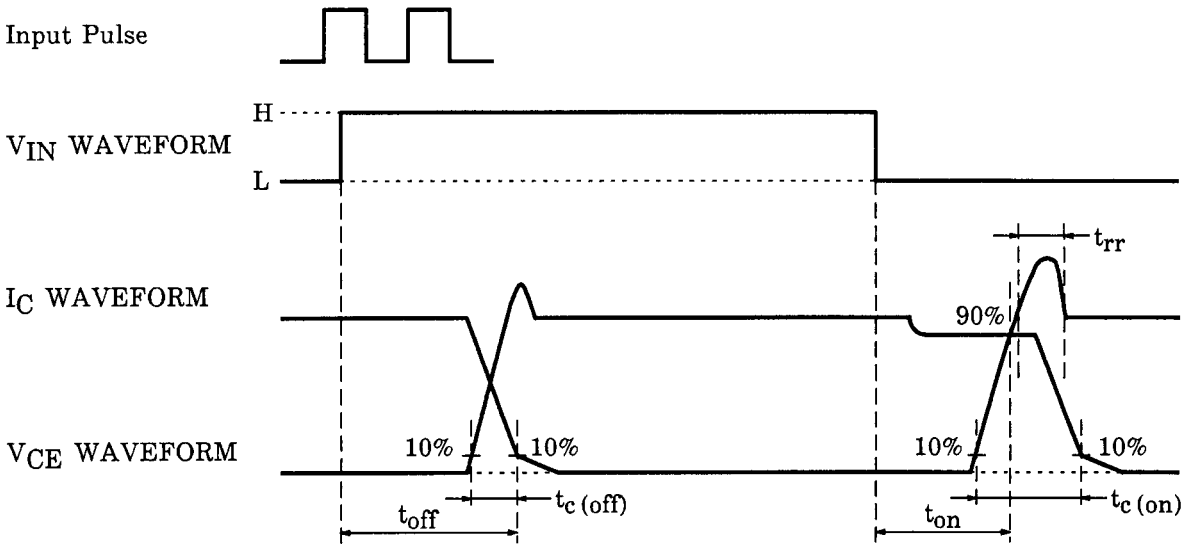
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Control circuit current		I_D	V_D = 15V	—	20	30	mA
Input on signal voltage		$V_{IN\ (on)}$	V_D = 15V, I_C = 400mA	0.9	1.1	1.3	V
Fault output current	Protection	$I_{FO\ (on)}$	V_D = 15V	8	10	12	mA
	Normal	$I_{FO\ (off)}$		—	—	1	
Over current protection trip level		OC	V_D = 15V, T_j = 125°C	560	640	—	A
Short circuit protection trip level		SC	V_D = 15V, T_j = 125°C	840	960	—	A
Over current cut-off time		$t_{off\ (OC)}$	V_D = 15V	—	10	—	μs
Over temperature protection	Trip level	OT	Case temperature	111	118	125	°C
	Reset level	OTr		93	100	107	
Control supply under voltage protection	Trip level	UV	—	11.3	12.0	12.7	V
	Reset level	UVr		11.8	12.5	13.2	
Fault output pulse width		t_{FO}	V_D = 15V	1	2	3	ms

c. Thermal Resistance (T_j = 25°C)

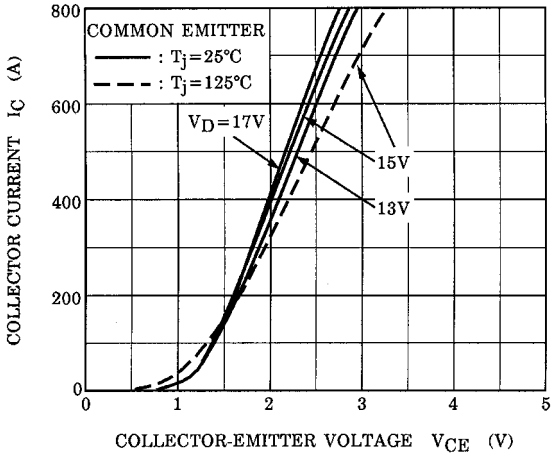
Characteristic	Symbol	Test Condition	MIN	TYP.	MAX	Unit
Junction to case thermal resistance	$R_{th\ (j-c)}$	IGBT	—	—	0.078	°C / W
		FRD	—	—	0.208	
Case to fin thermal resistance	$R_{th\ (c-f)}$	Compound is applied	—	0.05	—	°C / W

Note 1: Switching time test circuit & timing chart

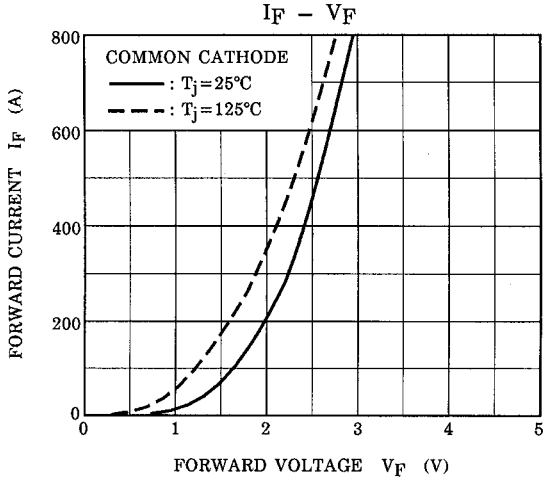




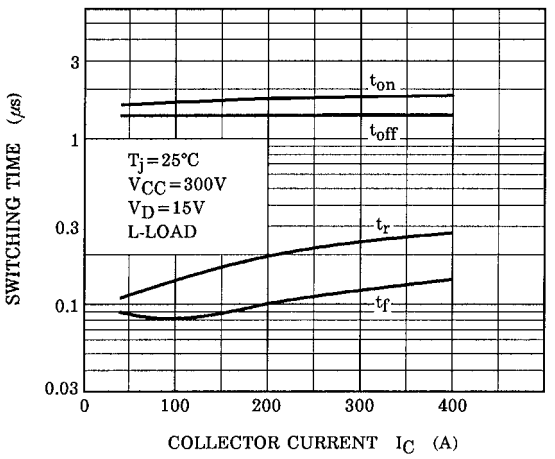
I_C – V_{CE}



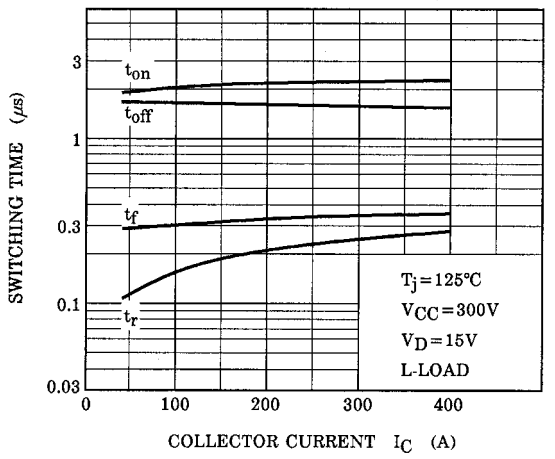
I_F – V_F



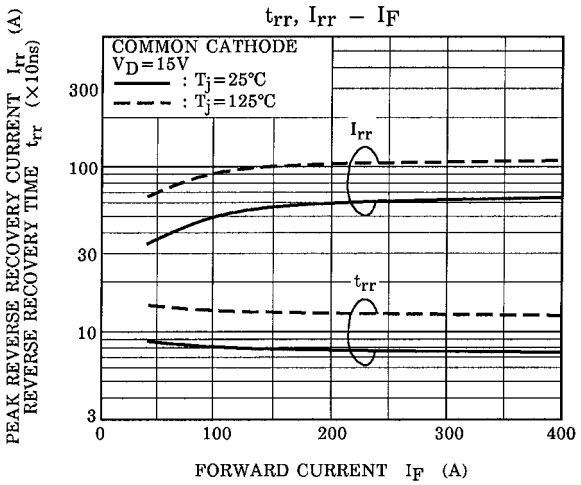
SWITCHING TIME – I_C



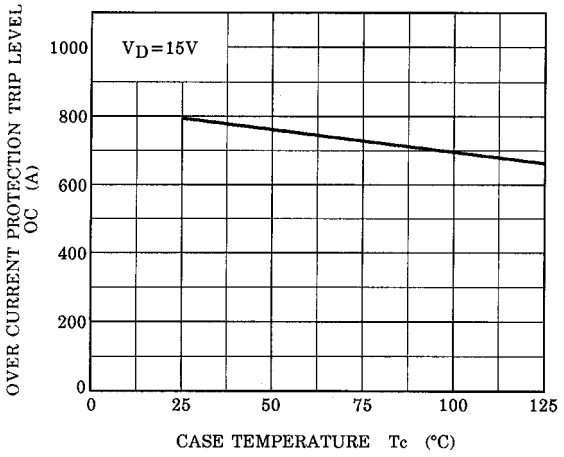
SWITCHING TIME – I_C



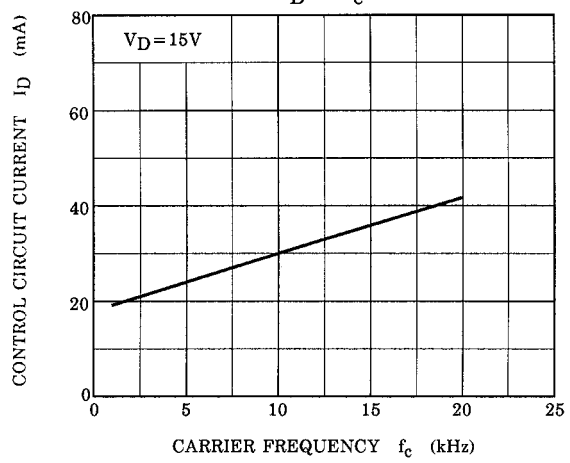
t_{rr}, I_{rr} – I_F



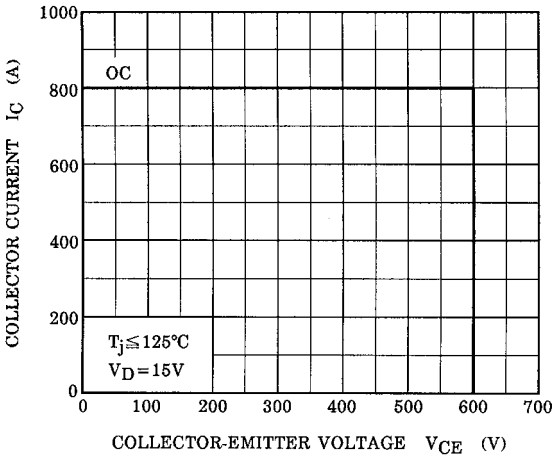
OC – Tc



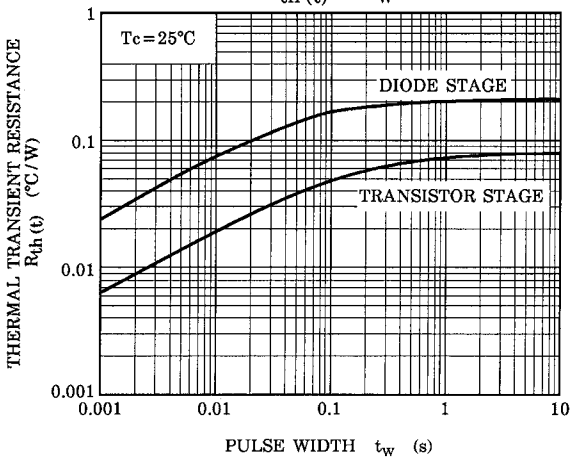
$I_D - f_c$



REVERSE BIAS SOA

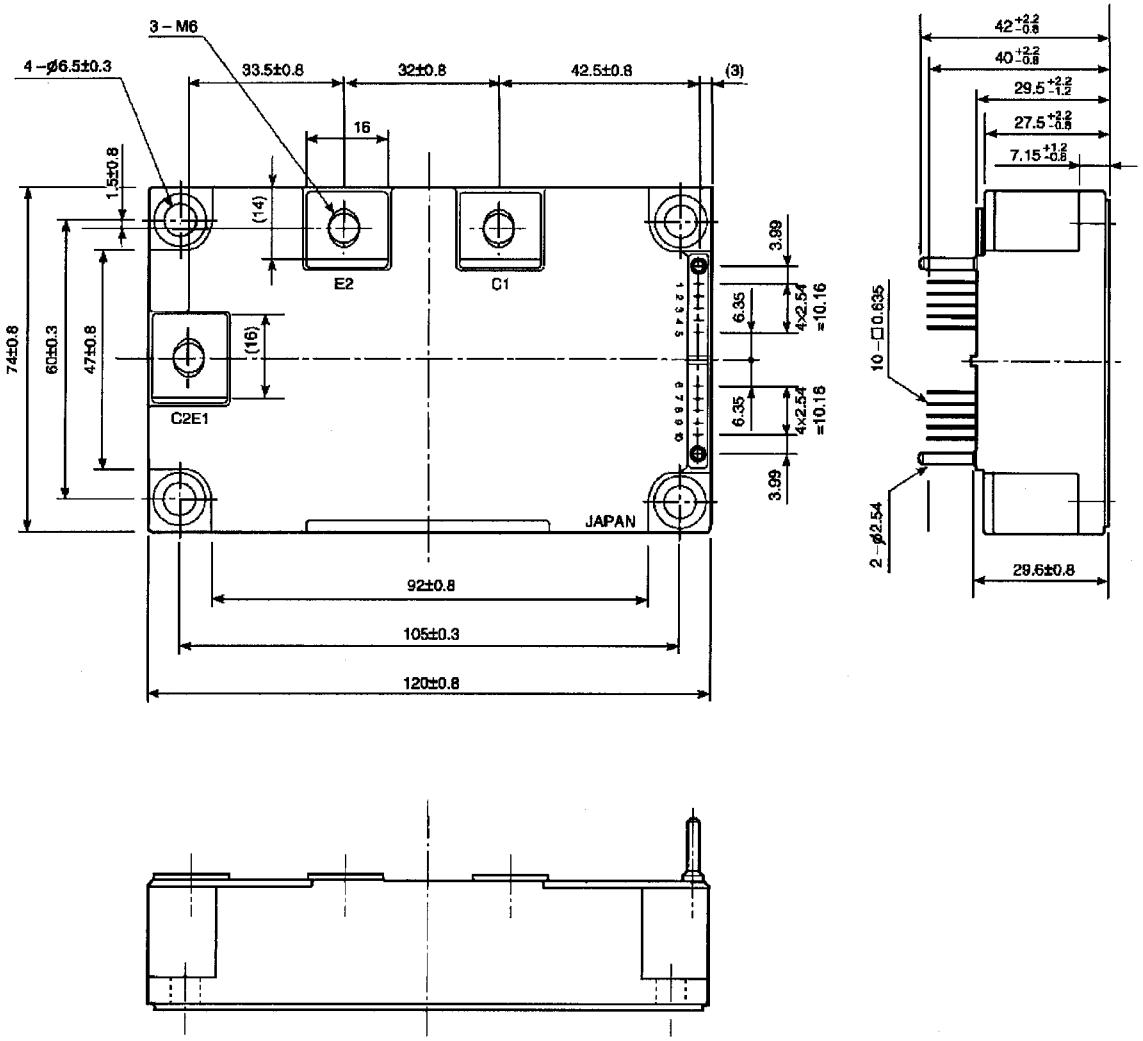


$R_{th\,(t)} - t_w$



Package Dimensions: TOSHIBA 2-121A1A

Unit: mm



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